

# VHF variable capacitance double diode Rev. 03 — 1 July 2004

**Product data sheet** 



# 1.1 General description

The BB804 is a variable capacitance double diode with a common cathode, fabricated in planar technology and encapsulated in the SOT23 small plastic SMD package.

# 1.2 Features

- Selected capacitance range
- Small plastic SMD package
- C8: 26 pF; ratio: 1.7
- Low series resistance.

# 1.3 Applications

Electronic tuning in FM radio applications.

#### **Pinning information** 2.

Table 1: **Pinning** 

Pin	Description	Simplified outline	Symbol		
1	anode (a1)		_		
2	anode (a2)	3	3		
3	common cathode	12	1 - 1 - 2 - 2 - 2 - 2 - 2		

#### **Ordering information** 3.

Table 2: **Ordering information** 

Type number	Package			
	Name	Description	Version	
BB804	-	plastic surface mounted package; 3 leads	SOT23	



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# 4. Marking

Table 3: Marking

Type number	Marking code [1]
BB804	16*

<sup>[1] \* =</sup> p: made in Hong Kong.

# 5. Limiting values

Table 4: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode	)				
$V_R$	continuous reverse voltage		-	18	V
l <sub>F</sub>	continuous forward current		-	50	mA
T <sub>stg</sub>	storage temperature		<b>–</b> 55	+150	°C
Tj	junction temperature		-55	+125	°C

# 6. Characteristics

**Table 5: Characteristics** 

 $T_i = 25 \,^{\circ}C$  unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I <sub>R</sub>	reverse current	see Figure 2				
		V <sub>R</sub> = 16 V	-	-	20	nA
		V <sub>R</sub> = 16 V; T <sub>j</sub> = 60 °C	-	-	200	nA
r <sub>s</sub>	diode series resistance	f = 100 MHz	[1] _	0.2	-	Ω
C <sub>d</sub>	diode capacitance	V <sub>R</sub> = 2 V; f = 1 MHz; see <u>Figure 1</u> and <u>Figure 3</u>	42	-	46.5	pF
$\frac{C_{d(2V)}}{C_{d(8V)}}$	capacitance ratio	f = 1 MHz	1.65	-	1.75	

<sup>[1]</sup>  $V_R$  is the value at which  $C_d$  = 38 pF.

<sup>\* =</sup> t: made in Malaysia.

<sup>\* =</sup> W: made in China.

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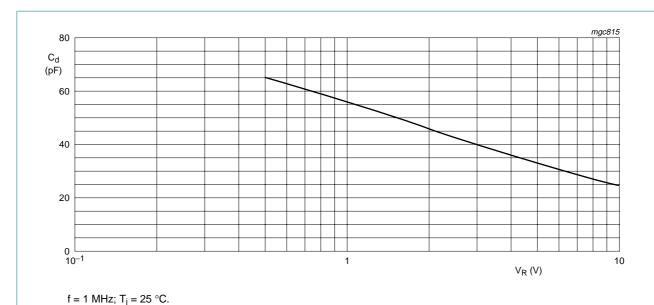


Fig 1. Diode capacitance as a function of reverse voltage; typical values.

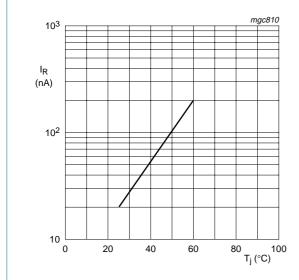


Fig 2. Reverse current as a function of junction temperature; maximum values.

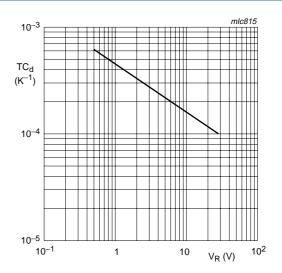


Fig 3. Temperature coefficient of diode capacitance as a function of reverse voltage; typical values.



# **Package outline**

### Plastic surface mounted package; 3 leads

SOT23

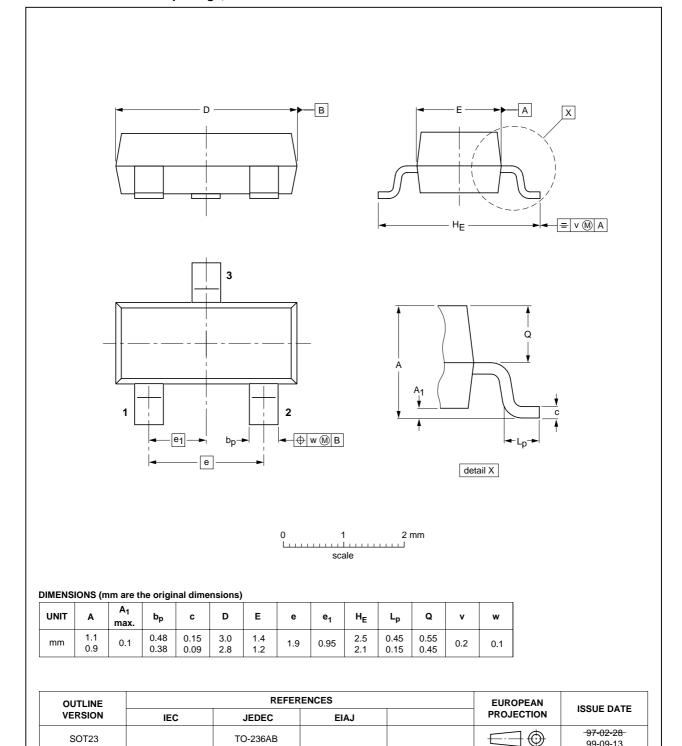


Fig 4. Package outline.

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# 8. Revision history

# Table 6: Revision history

Document ID	Release date	Data sheet status	Change notice	Order number	Supersedes
BB804_3	20040630	Product data sheet	-	9397 750 13386	BB804_2
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the new presentation and information standard of Philips Semiconductors</li> <li>Table 3: marking code changed.</li> </ul>				
BB804_2	19981125	Product data sheet	-	9397 750 04717	BB804_1
BB804_1	19960503	-	-	-	-

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#### 9. Data sheet status

Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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- [3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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